Erratum to: Ultra-high current gain tunneling hot-electron transfer amplifier based on vertical van der Waals heterojunctions

Xu Zhao^{1,2,§} (✉), Peng Chen^{1,2,§}, Xingqiang Liu¹ (✉), Guoli Li¹, Xuming Zou¹, Yuan Liu¹, Qilong Wu¹, Yufang Liu² (✉), Woo Jong Yu³, and Lei Liao¹

¹ Key Laboratory for Micro/Nano Optoelectronic Devices of Ministry of Education & Hunan Provincial Key Laboratory of Low-Dimensional Structural Physics and Devices, School of Physics and Electronics, Hunan University, Changsha 410082, China

² School of Physics, Henan Normal University, Xinxiang 453007, China

³ Department of Electronic and Electrical Engineering, Sungkyunkwan University, Suwon 440-746, Republic of Korea

[§] Xu Zhao and Peng Chen contributed equally to this work.

© Tsinghua University Press and Springer-Verlag GmbH Germany, part of Springer Nature 2020

Erratum to

Nano Research 2020, 13(8): 2085–2090
<https://doi.org/10.1007/s12274-020-2814-9>

On page 2085 and the first page of the ESM, the affiliation numbers of the authors were unfortunately misplaced, and there was no the university name (Hunan University) of the first affiliation of the authors.

Instead of

Xu Zhao^{1,§} (✉), Peng Chen^{1,2,§}, Xingqiang Liu² (✉), Guoli Li², Xuming Zou², Yuan Liu², Qilong Wu², Yufang Liu¹ (✉), Woo Jong Yu³, and Lei Liao²

¹ Key Laboratory for Micro/Nano Optoelectronic Devices of Ministry of Education & Hunan Provincial Key Laboratory of Low-Dimensional Structural Physics and Devices, School of Physics and Electronics, Changsha 410082, China

² Henan Normal University, School of Physics, Xinxiang 453007, China

³ Department of Electronic and Electrical Engineering, Sungkyunkwan University, Suwon 440-746, Republic of Korea

[§] Xu Zhao and Peng Chen contributed equally to this work.

It should read

Xu Zhao^{1,2,§} (✉), Peng Chen^{1,2,§}, Xingqiang Liu¹ (✉), Guoli Li¹, Xuming Zou¹, Yuan Liu¹, Qilong Wu¹, Yufang Liu² (✉), Woo Jong Yu³, and Lei Liao¹

¹ Key Laboratory for Micro/Nano Optoelectronic Devices of Ministry of Education & Hunan Provincial Key Laboratory of Low-Dimensional Structural Physics and Devices, School of Physics and Electronics, Hunan University, Changsha 410082, China

² School of Physics, Henan Normal University, Xinxiang 453007, China

³ Department of Electronic and Electrical Engineering, Sungkyunkwan University, Suwon 440-746, Republic of Korea

[§] Xu Zhao and Peng Chen contributed equally to this work.

The online version of the original article can be found at
<https://doi.org/10.1007/s12274-020-2814-9>

Address correspondence to Xingqiang Liu, liuxq@hnu.edu.cn; Xu Zhao, zhaoxu@htu.cn; Yufang Liu, yf-liu@henannu.edu.cn

TSINGHUA
UNIVERSITY PRESS

Springer